



DN0150ALP4 / DN0150BLP4

50V NPN SMALL SIGNAL TRANSISTOR IN DFN1006

Features

- Epitaxial Die Construction
- Ultra-Small Leadless Surface Mount Package
- Ultra Low Profile (0.4mm max)
- Complementary PNP Type: DP0150ALP4/DP0150BLP4
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

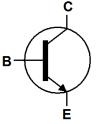
Mechanical Data

- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208 ⁽¹⁾
- Weight: 0.0008 grams (approximate)

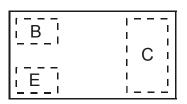
X2-DFN1006-3



Bottom View



Device Symbol



Top View Pin Configuration

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DN0150ALP4-7	Т3	7	8	3,000
DN0150ALP4-7B	Т3	7	8	10,000
DN0150BLP4-7	T4	7	8	3,000
DN0150BLP4-7B	T4	7	8	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

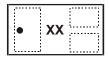
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

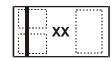
Marking Information

DN0150ALP4-7 DN0150BLP4-7



Top View Dot Denotes Collector Side

DN0150ALP4-7B DN0150BLP4-7B



Top View Bar Denotes Base and Emitter Side XX = Product Type Marking Code (See Ordering Information)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	60	V	
Collector-Emitter Voltage	V _{CEO}	50	V	
Emitter-Base Voltage	V _{EBO}	5	V	
Collector Current – Continuous	Ιc	100	mA	
Peak Pulse Collector Current	I _{CM}	200	mA	
Base Current	IB	30	mA	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)	PD	450	mW	
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	278	°C/W	
Thermal Resistance, Junction to Leads (Note 6)	R _{θJL}	110	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Electrical Characteristics (@T_A = $+25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage		BV _{CBO}	60	—	—	V	$I_{\rm C} = 10 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Volt	age (Note 8)	BV _{CEO}	50	—	—	V	I _C = 1mA, I _B = 0
Emitter-Base Breakdown Voltage		BV _{EBO}	5	—	—	V	$I_{\rm E}$ = 10µA, $I_{\rm C}$ = 0
Collector Cut-Off Current		I _{CBO}	_		0.1	μA	$V_{CB} = 60V, I_E = 0$
Emitter Cut-Off Current		I _{EBO}	_		0.1	μA	$V_{EB} = 5V, I_{C} = 0$
ON CHARACTERISTICS (Note 8	3)						
Collector-Emitter Saturation Volta	ge	V _{CE(SAT)}	—	0.10	0.25	V	I _C = 100mA, I _B = 10mA
DC Current Gain DN0150ALP4			120	_	240		$V_{CE} = 6V, I_{C} = 2mA$
	DN0150BLP4	h _{FE}	200	—	400		VCE - 0V, IC - 2IIIA
SMALL SIGNAL CHARACTERIS	TICS				-		
Transition Frequency		f _T	60	—	—	MHz	V _{CE} = 10V, I _E = -1mA f = 30MHz
Output Capacitance		C _{ob}	_	1.3	_	pF	V _{CB} = 10V, I _E = 0, f = 1MHz

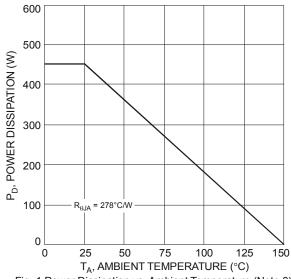
Notes: 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state. The entire exposed collector pad is attached to the heat sink.

6. Thermal resistance from junction to solder-point (at the end of the collector lead).

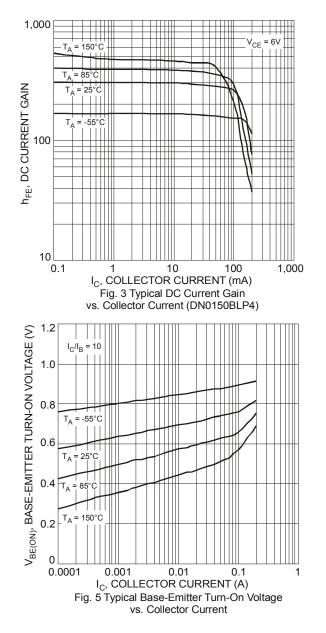
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%

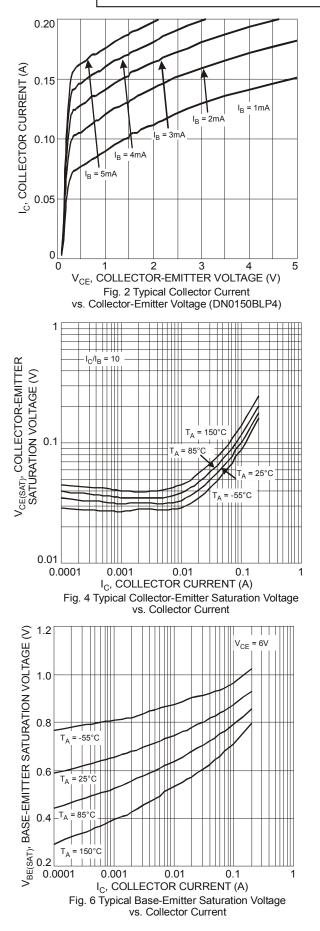








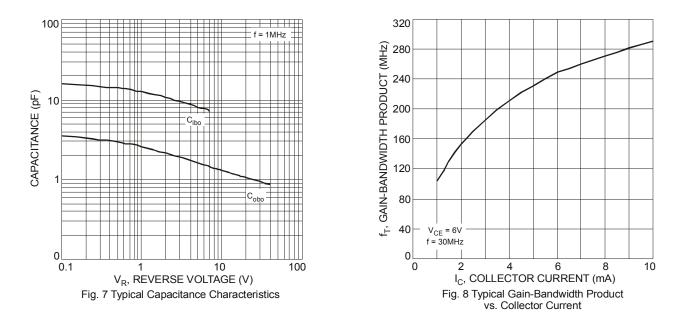
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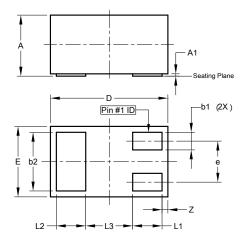


DN0150ALP4 / DN0150BLP4



Package Outline Dimensions

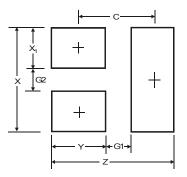
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



X2-DFN1006-3					
Dim	Min	Max	Тур		
Α	_	0.40			
A1	0	0.05	0.02		
b1	0.10	0.20	0.15		
b2	0.45	0.55	0.50		
D	0.95	1.05	1.00		
ш	0.55	0.65	0.60		
e			0.35		
L1	0.20	0.30	0.25		
L2	0.20	0.30	0.25		
L3	_	-	0.40		
All	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Y	0.4
С	0.7



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